PNP/NPN Epitaxial Planar Silicon Transistors



2SB1296/2SD1936

AF Amplifier Applications

Applications

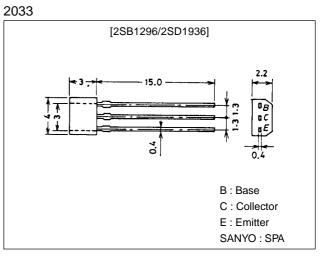
· AF power amplifier, medium-speed switching, smallsized motor drivers.

Features

- · Large current capacity.
- · Low collector to emitter saturation voltage.
- · Wide ASO.

Package Dimensions

unit:mm



():2SB1296

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)15	V
Collector-to-Emitter Voltage	VCEO		(–)15	V
Emitter-to-Base Voltage	VEBO		(–)5	V
Collector Current	IC		(-)0.8	A
Collector Current (Pulse)	ICP		(–)3	A
Collector Dissipation	PC		300	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings			
Falanetei	Symbol	Conditions	mir		typ	<u> </u>	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)12V, I _E =0				(–)100	nA
Emitter Cutoff Current	IEBO	V _{EB} =(-)4V, I _C =0				(–)100	nA
	hFE1	V _{CE} =(-)2V, I _C =(-)50mA	14)*		(560)*	
DC Current Gain						800*	
	h _{FE} 2	V _{CE} =(-)2V, I _C =(-)800mA		30			
* : The 2SB1296/2SD1936 are classified	by 50mA here as foll	ows :					

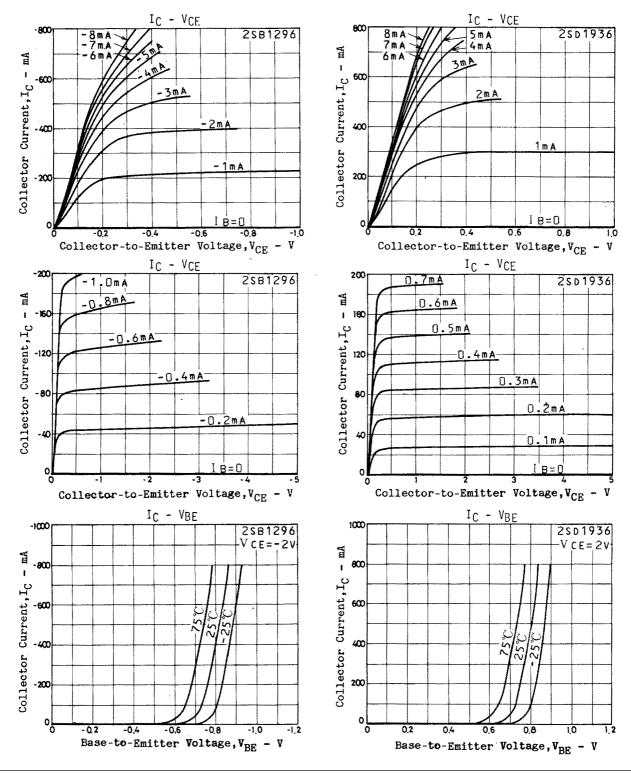
2SB1296	140	S	280	200	Т	400	280	U	560			
2SB1936	140	S	280	200	Т	400	280	U	560	400	V	800

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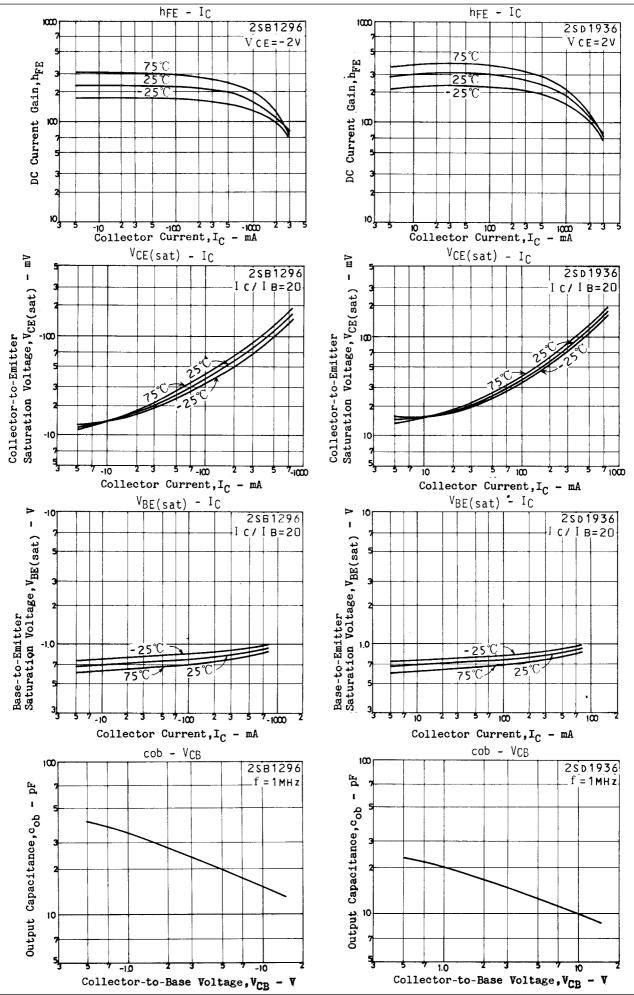
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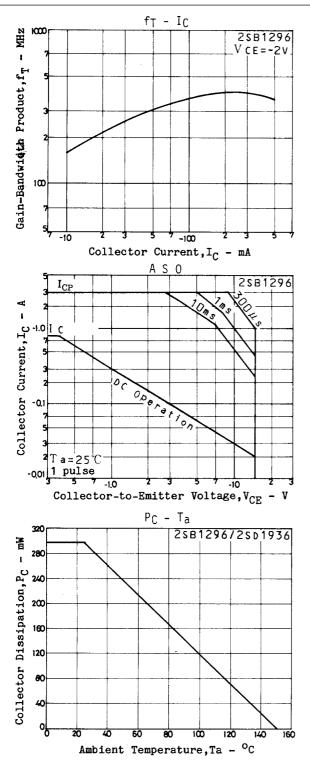
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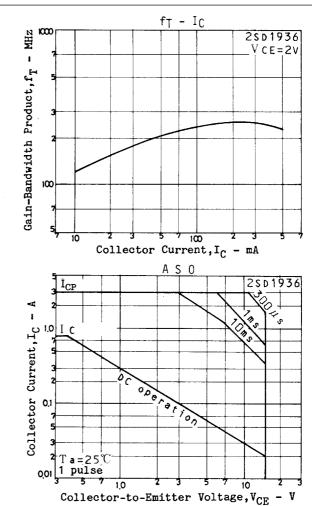
Parameter	Symbol	Conditions		Unit			
Falameter	Symbol	Conditions	min	typ	max	Unit	
Gain-Bandwidth Product	fT	V _{CE} =(-)2V, I _C =(-)50mA		(300)		MHz	
				200		MHz	
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		(15)		pF	
				10		pF	
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} 1	I _C =(-)5mA, I _B =(-)0.5mA		(–)10	(–)25	mV	
	V _{CE(sat)} ²	I _C =(-)400mA, I _B =(-)20mA		(–)100	(–)200	mV	
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)400mA, I _B =(-)20mA		(–)0.9	(–)1.2	V	
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)10µA, I _E =0	(–)15			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	(–)15			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)10μA, I _C =0	(–)5			V	



2SB1296/2SD1936







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